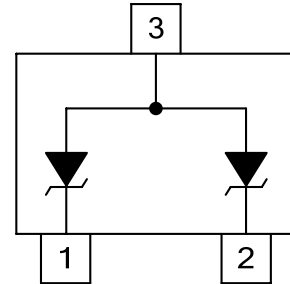


Description

SET23AXXL02 series of transient voltage suppressor (TVS) are designed to protect components which are connected to data and transmission lines from voltage surges caused by electrostatic discharge (ESD), electrical fast transients (EFT) and lightning.

TVS diodes are characterized by their high surge capability, low operating and clamping voltages, and fast response time.



Features

- IEC61000-4-2 ESD 15KV Air, 8KV contact compliance
- Protects one bidirectional line or two unidirectional lines
- Working voltage: 3.3V, 5V, 12V, 15V, 24V and 36V
- Low leakage current
- Low operating and clamping voltages
- Solder reflow temperature: Pure Tin-Sn, 260~270°C

Applications

- Cellular handsets and accessories
- Personal digital assistants (PDA's)
- Portable instrumentation
- Set Top Box (STB)
- Servers, notebook, and desktop PC
- Wireless bus protection
- RS-232, RS-422, RS-423 protection

Maximum Ratings

Rating	Symbol	Value	Unit
ESD voltage (Contact discharge)	V_{ESD}	± 8	kV
ESD voltage (Air discharge)		± 15	
Storage & operating temperature range	T_{STG}, T_J	-55~+150	$^{\circ}C$

Electrical Characteristics ($T_J=25^{\circ}C$)
SET23A03L02

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				3.3	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1mA$	4			V
Reverse leakage current	I_R	$V_R=3.3V$ Each I/O pin			5	μA
Clamping voltage ($t_p=8/20\mu s$)	V_C	$I_{PP}=1A$			7.5	V
Clamping voltage ($t_p=8/20\mu s$)	V_C	$I_{PP}=10A$			15	V
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		200		pF

SET23A05L02

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				5	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1mA$	6			V
Reverse leakage current	I_R	$V_R=5V$ Each I/O pin			5	μA
Clamping voltage ($t_p=8/20\mu s$)	V_C	$I_{PP}=1A$			9.8	V
Clamping voltage ($t_p=8/20\mu s$)	V_C	$I_{PP}=15A$			20	V
Off state junction capacitance	C_J	0Vdc, f=1MHz Between I/O pins and GND		220		pF

Electrical Characteristics (T_J=25°C)
SET23A12L02

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V _{RWM}				12	V
Reverse breakdown voltage	V _{BR}	I _{BR} =1mA	13.3			V
Reverse leakage current	I _R	V _R =12V Each I/O pin			1	μA
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =1A			19	V
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =10A			25.9	V
Off state junction capacitance	C _J	0Vdc, f=1MHz Between I/O pins and GND		100		pF

SET23A15L02

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V _{RWM}				15	V
Reverse breakdown voltage	V _{BR}	I _{BR} =1mA	16.7			V
Reverse leakage current	I _R	V _R =15V Each I/O pin			1	μA
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =1A			24	V
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =10A			30	V
Off state junction capacitance	C _J	0Vdc, f=1MHz Between I/O pins and GND		90		pF

SET23A24L02

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V _{RWM}				24	V
Reverse breakdown voltage	V _{BR}	I _{BR} =1mA	26.7			V
Reverse leakage current	I _R	V _R =24V each I/O pin			1	μA
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =1A			43	V
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =5A			49	V
Off state junction capacitance	C _J	0Vdc, f=1MHz Between I/O pins and GND		80		pF

Electrical Characteristics (T_J=25°C)

SET23A36L02

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V _{RWM}				36	V
Reverse breakdown voltage	V _{BR}	I _{BR} =1mA	40			V
Reverse leakage current	I _R	V _R =36V each I/O pin			1	μA
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =1A			51	V
Clamping voltage (tp=8/20μs)	V _C	I _{PP} =5A			76.8	V
Off state junction capacitance	C _J	0Vdc, f=1MHz Between I/O pins and GND		70		pF

Typical Characteristics Curves

Figure 1. Power Derating Curve

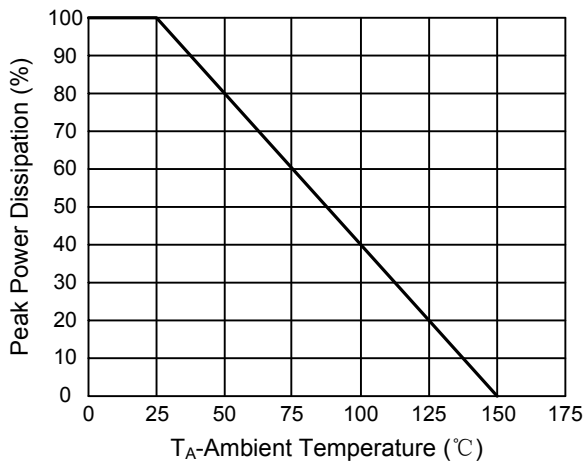


Figure 2. Pulse Waveforms

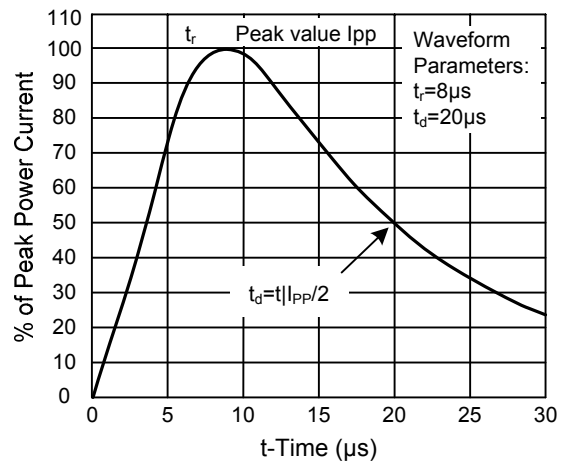


Figure 3. Forward Voltage vs. Forward Current

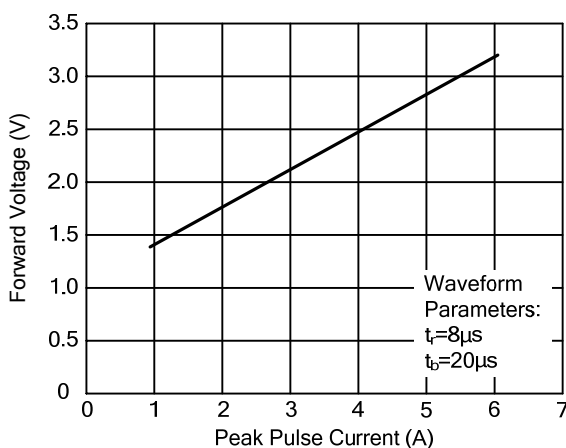
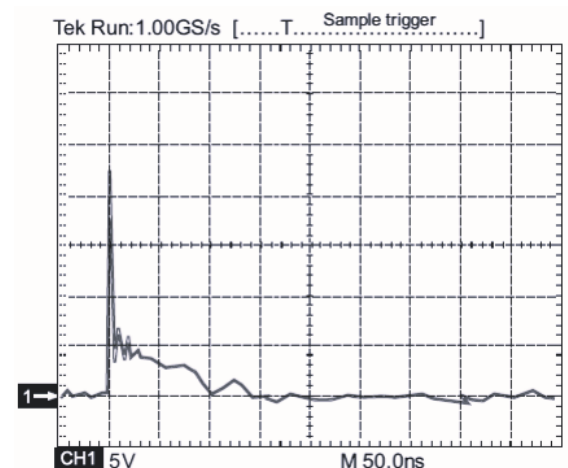
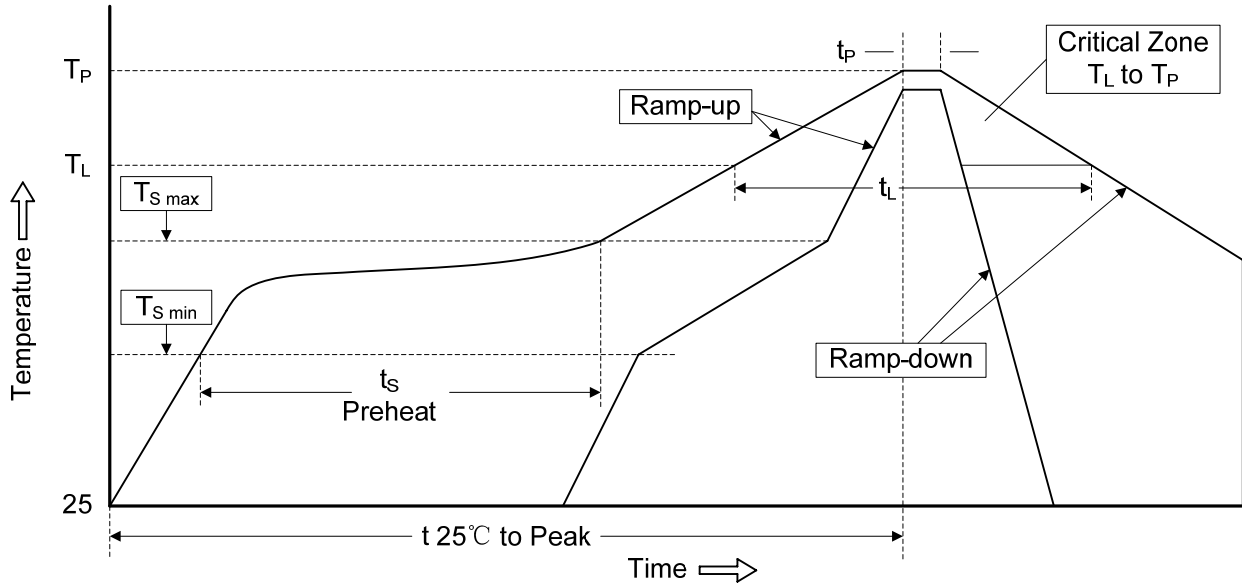


Figure 4. ESD Clamping(8kV Contact IEC61000-4-2)



Recommended Soldering Conditions

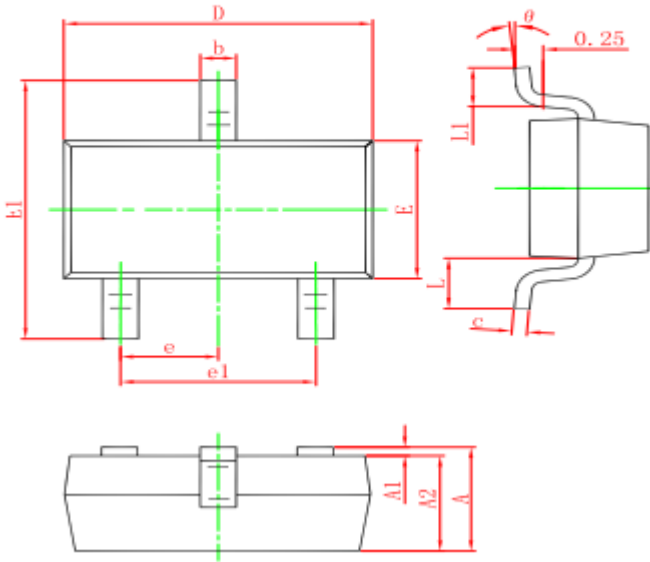
Reflow Soldering



Recommended Conditions

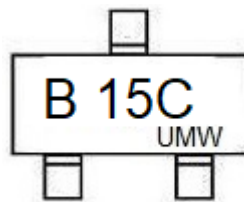
Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3°C/second max.
Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s)	150°C 200°C 60-180 seconds
$T_{S\ max}$ to T_L -Ramp-up Rate	3°C/second max.
Time maintained above: -Temperature (T_L) -Time (t_L)	217°C 60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_p)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

SOT-23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Marking



Ordering information

Order code	Package	Baseqty	Deliverymode	Marking
UMW SET23A03L02	SOT-23	3000	Tape and reel	B 03C UMW
UMW SET23A05L02	SOT-23	3000	Tape and reel	B 05C UMW
UMW SET23A12L02	SOT-23	3000	Tape and reel	B 12C UMW
UMW SET23A15L02	SOT-23	3000	Tape and reel	B 15C UMW
UMW SET23A24L02	SOT-23	3000	Tape and reel	B 24C UMW
UMW SET23A36L02	SOT-23	3000	Tape and reel	B 36C UMW

单击下面可查看定价，库存，交付和生命周期等信息

[>>UMW\(友台半导体\)](#)